

Synthesis of SnO₂ Nanosized Powder by Mechanochemical Method for Sensing of H₂S

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Abstract

In a mechanochemical process SnCl₂ and Ca(OH)₂ powders were milled in a ball-mill at room temperature and in an air atmosphere. No X-ray diffraction peaks were observed for the as-milled powder but heat treatment above 300 °C causes the appearance of only SnO₂ and CaCl₂ phases confirming that solid-state displacement reactions have been started during a ball-milling without external heating. Removal of the CaCl₂ by-product was carried out by washing the powder with distilled water using a centrifuge. The powders obtained were impregnated with an aqueous solution of (AgNO₃ or La(NO₃)₃·6H₂O) followed by heat treatment at a low temperature (450 °C) which was still sufficient to decompose the salt and to distribute the surface additive on a fine scale. Higher decomposition temperatures may cause agglomeration of the additive particles. Surface-doped SnO₂ powders were then mixed in polyvinyl alcohol (PVA) solution to form pastes and coated onto Al₂O₃ substrates with comb-type Au electrodes and sintered. On exposure to 1 ppm of H₂S gas the Ag₂O-SnO₂

thick film has higher sensitivity compared to that of the undoped and lanthanum-doped SnO₂. High sensitivity to H₂S gas was gained due to fine crystallites of synthesized tin dioxide powder with unagglomerated surface microstructure. The BET particle size was less than 25 nm. Surface doping by impregnation seemed to be effective since the small SnO₂ crystallite size was maintained and it was controlled by varying the concentration of solution and time. The results show that by an appropriate powder synthesis method and control of surface doping of SnO₂ can be modified for use as a H₂S gas sensor in the concentration range below 1 ppm.

Key words: ball-milling, heat treatment, by-product, SnO₂, surface doping, XRD, H₂S adsorption, electronic conductivity.